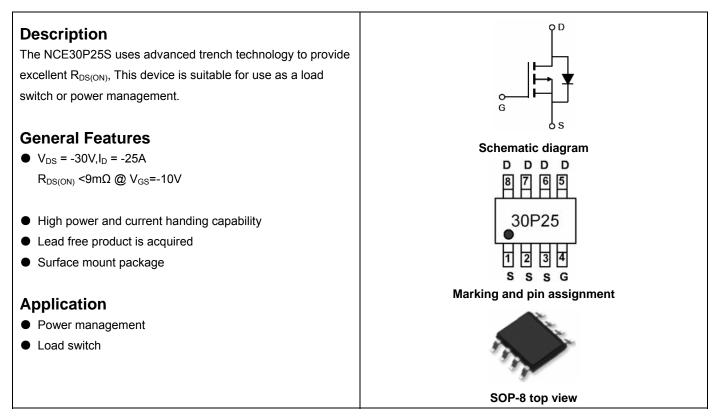


NCE P-Channel Enhancement Mode Power MOSFET



Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
30P25	NCE30P25S	SOP-8	Ø330mm	12mm	2500 units

Absolute Maximum Ratings (T_A=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	-30	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	I _D	-25	А
Drain Current-Pulsed (Note 1)	I _{DM}	-70	A
Maximum Power Dissipation	PD	3.5	W
Operating Junction and Storage Temperature Range	T _J ,T _{STG}	-55 To 150	°C

Thermal Characteristic

Thermal Resistance, Junction-to-Ambient (Note 2)	R _{θJA}	36	°C/W
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Electrical Characteristics (T_A=25[°]C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =-250µA	-30	-33	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =-30V, V_{GS} =0V	-	-	-1	μA



Pb Free Product

NCE30P25S

Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=-250\mu A$	-1.0	-1.5	-2.5	V
Desir Osumos Or Otata Desistance	R _{DS(ON)}	V _{GS} =-10V, I _D =-15A	-	6.4	9	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =-4.5V, I _D =-10A	-	8.3	14	
Forward Transconductance	g fs	V _{DS} =-10V,I _D =-15A	30	-	-	S
Dynamic Characteristics (Note4)	·					
Input Capacitance	C _{lss}		-	3960	-	PF
Output Capacitance	Coss	– V _{DS} =-15V,V _{GS} =0V, – F=1.0MHz	-	486	-	PF
Reverse Transfer Capacitance	Crss		-	268	-	PF
Switching Characteristics (Note 4)	·	·				
Turn-on Delay Time	t _{d(on)}		-	20	-	nS
Turn-on Rise Time	tr	V _{DD} =-15V, ID=-10A,	-	13	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =-10V,R _{GEN} =3 Ω	-	55	-	nS
Turn-Off Fall Time	t _f		-	21	-	nS
Total Gate Charge	Qg		-	65	-	nC
Gate-Source Charge	Q _{gs}	V _{DS} =-15V,I _D =-10A,V _{GS} =-10V	-	12	-	nC
Gate-Drain Charge	Q _{gd}		-	14	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =-25A	-	-	-1.2	V

Notes

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board, $t \le 10$ sec.
- **3.** Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.
- 4. Guaranteed by design, not subject to production



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Typical Electrical and Thermal Characteristics

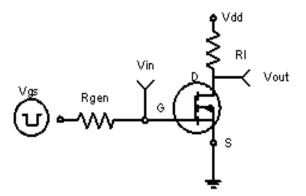
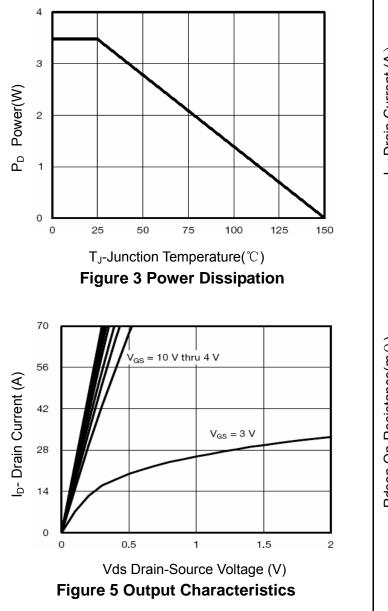


Figure 1 Switching Test Circuit



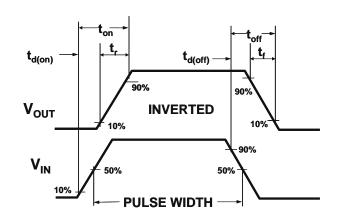
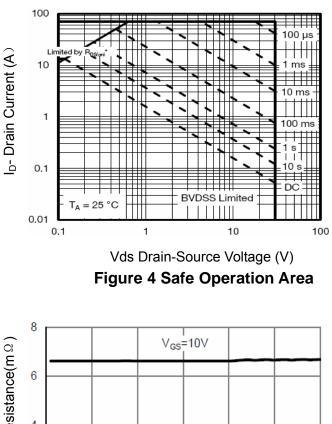
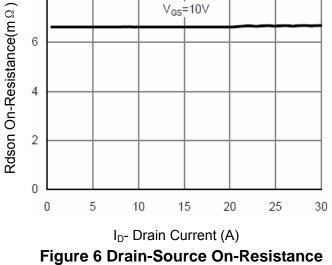


Figure 2 Switching Waveforms



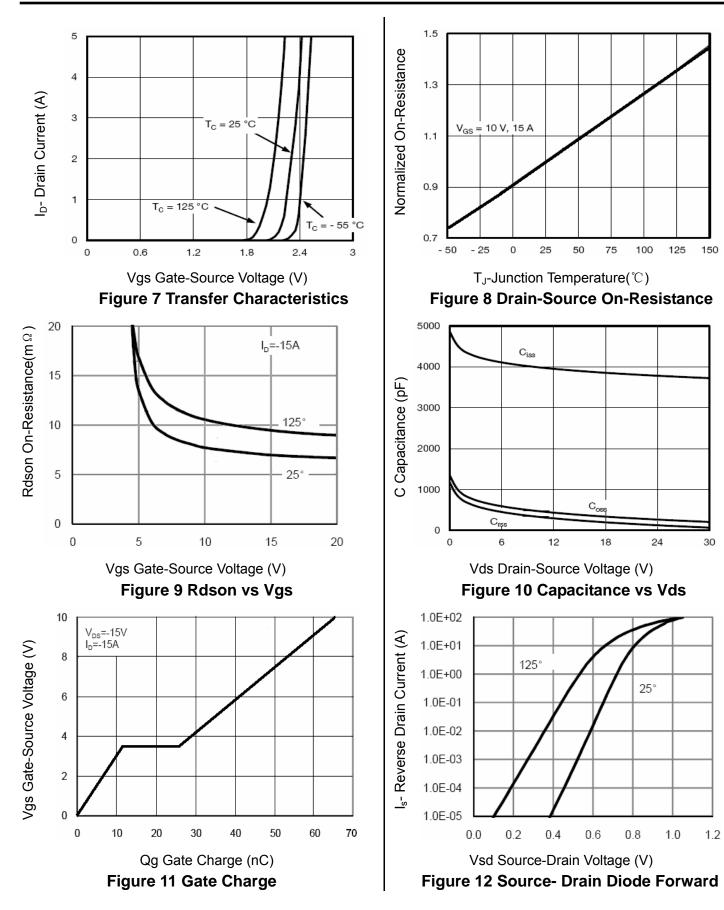


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NCE30P25S







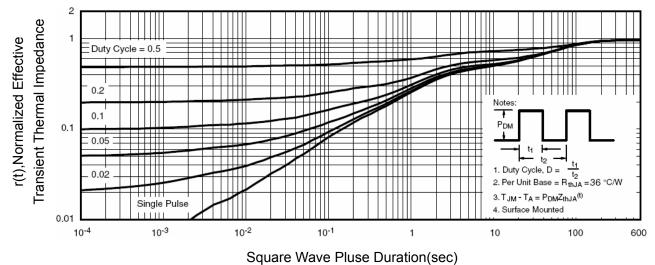
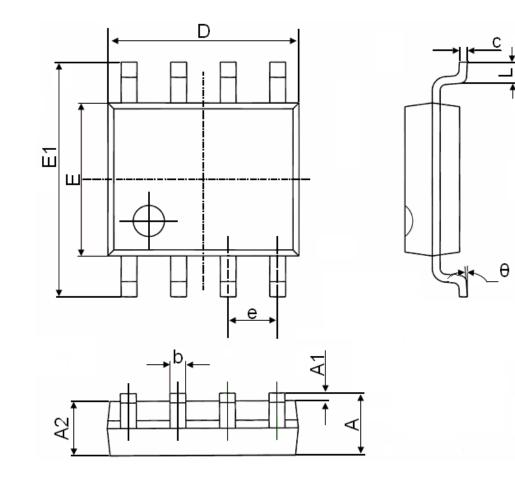


Figure 13 Normalized Maximum Transient Thermal Impedance





SOP-8 Package Information



Symbol	Dimensions	n Millimeters	Dimensions In Inches		
	Min.	Max.	Min.	Max.	
A	1.350	1.750	0.053	0.069	
A1	0.100	0.250	0.004	0.010	
A2	1.350	1.550	0.053	0.061	
b	0.330	0.510	0.013	0.020	
с	0.170	0.250	0.006	0.010	
D	4.700	5.100	0.185	0.200	
E	3.800	4.000	0.150	0.157	
E1	5.800	6.200	0.228	0.244	
е	1.270	(BSC)	0.050	(BSC)	
L	0.400	1.270	0.016	0.050	
θ	0°	8°	0°	8°	





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